RENESAS

2SB562

Silicon PNP Epitaxial

REJ03G0646-0200
(Previous ADE-208-1024)
Rev.2.00
Aug.10.2005

Application

- Low frequency power amplifier
- Complementary pair with 2SD468

Outline

RENESAS Package code: PRSS0003DC-A
(Package name: TO-92 Mod)

1. Emitter
2. Collector
3. Base

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	–25	V
Collector to emitter voltage	V_{CEO}	–20	V
Emitter to base voltage	V_{EBO}	–5	V
Collector current	I_C	–1.0	A
Collector peak current	$i_{C(peak)}$	–1.5	A
Collector power dissipation	P_C	0.9	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	–55 to +150	°C

Electrical Characteristics

(Ta = 25°C)

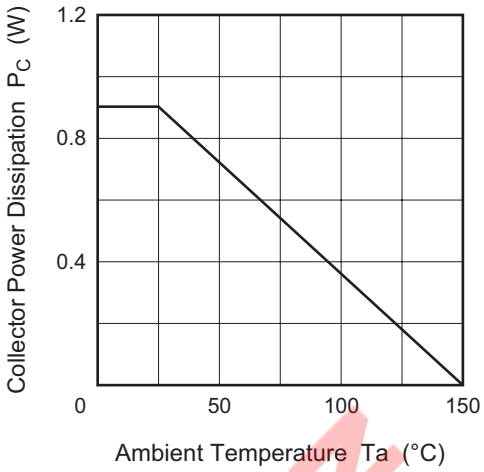
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	–25	—	—	V	I_C = –10 µA, I_E = 0
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	–20	—	—	V	I_C = –1 mA, R_{BE} = ∞
Emitter to base breakdown voltage	$V_{(BR)EBO}$	–5	—	—	V	I_E = –10 µA, I_C = 0
Collector cutoff current	I_{CBO}	—	—	–1.0	µA	V_{CB} = –20 V, I_E = 0
DC current transfer ratio	h_{FE}*[1]	85	—	240		V_{CE} = –2 V, I_C = –0.5 A (Pulse test)
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	–0.2	–0.5	V	I_C = –0.8 A, I_B = –0.08 A (Pulse test)
Base to emitter voltage	V_{BE}	—	–0.8	–1.0	V	V_{CE} = –2 V, I_C = –0.5 A (Pulse test)
Gain bandwidth product	f_T	—	350	—	MHz	V_{CE} = –2 V, I_C = –0.5 A (Pulse test)
Collector output capacitance	Cob	—	38	—	pF	V_{CB} = –10 V, I_E = 0 f = 1 MHz

Note: 1. The 2SB562 is grouped by h_{FE} as follows.

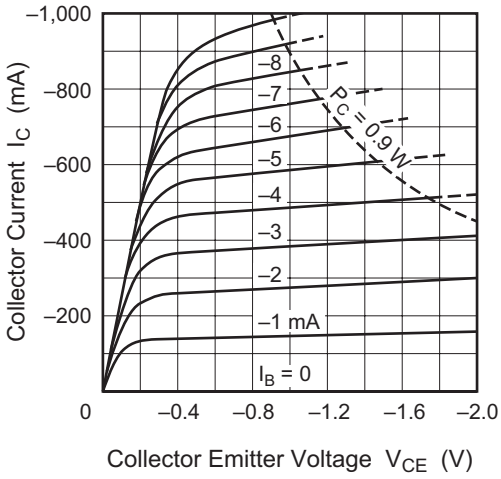
B	C
85 to 170	120 to 240

Main Characteristics

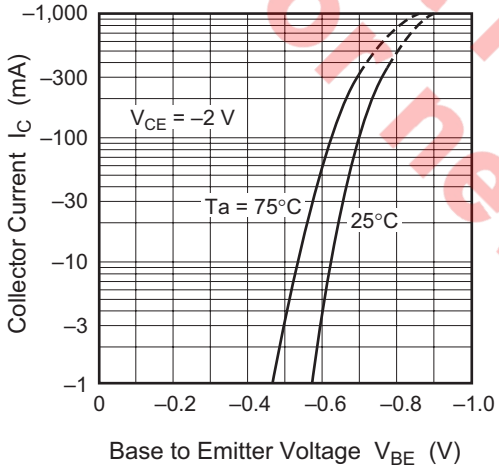
Maximum Collector Dissipation Curve



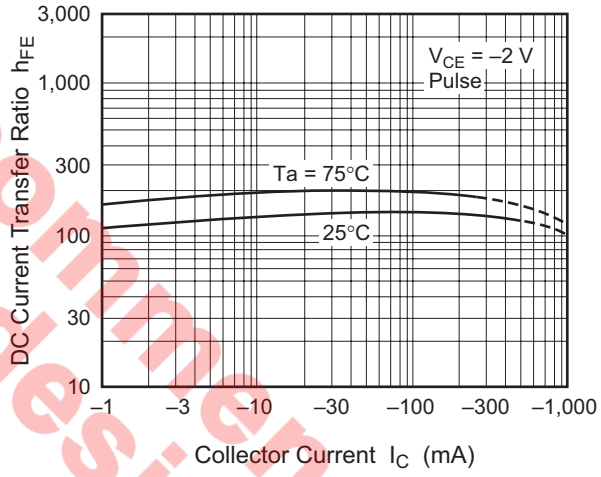
Typical Output Characteristics



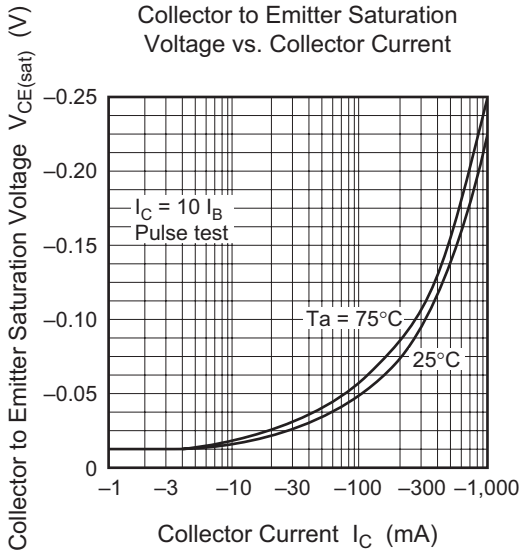
Typical Transfer Characteristics



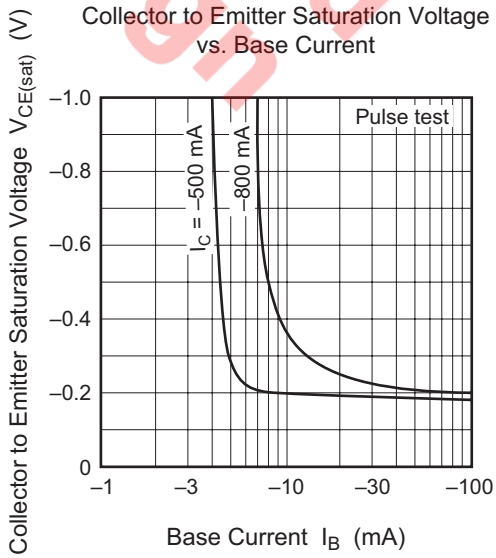
DC Current Transfer Ratio vs.Collector Current



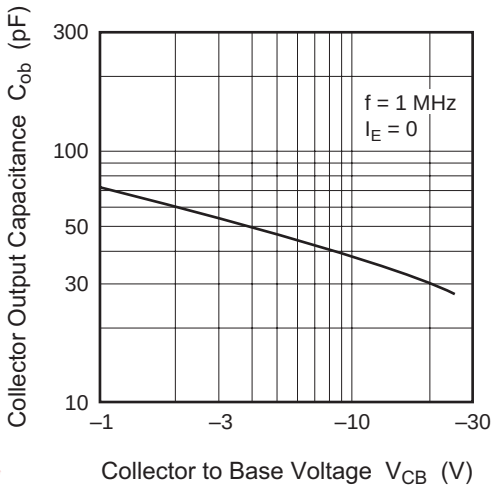
Collector to Emitter Saturation Voltage vs. Collector Current



Collector to Emitter Saturation Voltage vs. Base Current



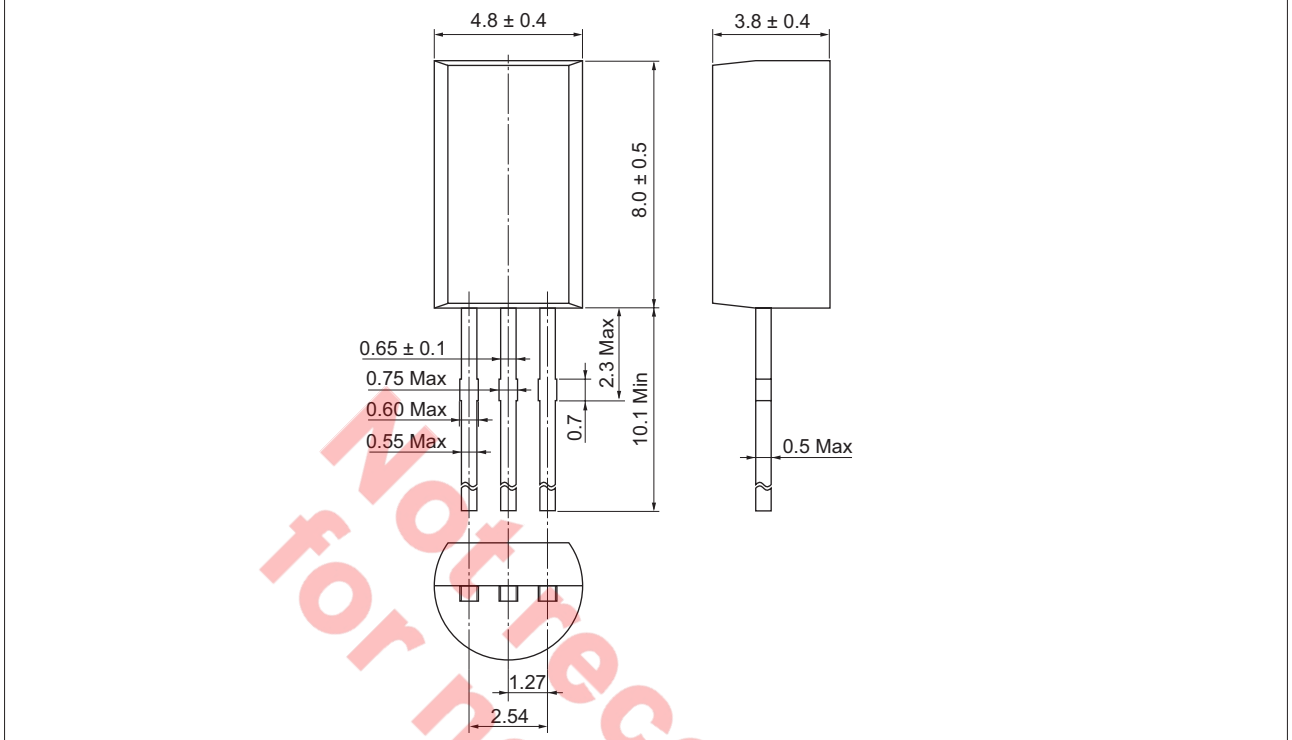
Collector Output Capacitance vs.
Collector to Base Voltage



Package Dimensions

JEITA Package Code	RENESAS Code	Package Name	MASS[Typ.]
SC-51	PRSS0003DC-A	TO-92 Mod / TO-92 ModV	0.35g

Unit: mm



Ordering Information

Part Name	Quantity	Shipping Container
2SB562BTZ-E 2SB562CTZ-E	2500	Hold Box, Radial Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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RENESAS SALES OFFICES

http://www.renesas.com

Refer to "**http://www.renesas.com/en/network**" for the latest and detailed information.

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